Hallogic Hall-effect Sensor Assembly OHB900



Features:

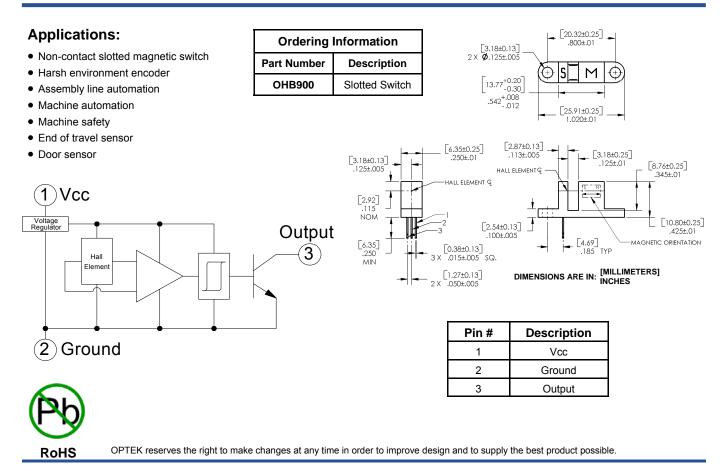
- Non-contact motion sensing
- Operates over a broad range of supply voltages (4.5 V to 25 V)
- Excellent temperature stability
- Hall element, linear amplifier and Schmitt trigger on a single Hallogic silicon chip
- · Performs in dirty environments over wide temperature range
- 0.125" (3.18 mm) wide gap



Description:

The OHB900 consists of a Hall-effect sensor similar to the OH180U and a rare earth magnet mounted in a lowcost plastic housing. The magnet produces optimum magnetic flux at the Hall-effect sensor location. The sensor has an open collector transistor output, which is activated when the slot is open. When the slot is blocked by a ferrous material that reduces the magnetic flux density at the Hall-effect sensor location, the open collector output transistor switches off. The device provides up to 25 mA of sink current. Output characteristics are constant at switching frequencies from DC to over 200 kHz.

The Uni-Polar turns on with a (logic level "0") after a sufficient magnetic field from the south pole of a magnet approaches the symbolized face of the device (Operating Point) and turns off (logic level "1") after the magnetic field reached a minimum value. This feature makes these sensors ideal for applications in non-contact switching operations.





Absolute Maximum Ratings (TA = 25° C unless otherwise noted)

Supply Voltage, V _{cc}	25 V
Storage Temperature Range, T _s	-50°C to +160° C
Operating Temperature Range, T _A	-40°C to +150° C
Lead Soldering Temperature (1/8 in. (3.2 mm) from case for 5 sec. with soldering iron)	260° C
Output ON Current, I _{SINK}	25 mA
Output OFF Voltage, V _{OUT}	25 V
Magnetic Flux Density, B	Unlimited

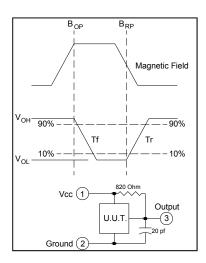
Electrical Characteristics (V_{CC} = 4.5 V to 24 V, T_A = 25° C unless otherwise noted)⁽²⁾

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
I _{CC}	Supply Current	-	4	7	mA	V _{CC} = 24 V, Output Off
V _{OL}	Output Saturation Voltage	-	100	400	mV	V_{CC} = 4.5 V, I _{OL} = 20 mA, Slot Open
I _{ОН}	Output Leakage Current	-	0.1	10	μA	V = 4.5 V, V_{OUT} = 24 V, Slot Blocked ⁽¹⁾
tr	Output Rise Time	-	0.21	1	μs	R _L = 820 Ω, C _L = 20 pF
t _f	Output Fall Time	-	0.1	1	μs	R _L = 820 Ω, C _L = 20 pF

Notes:

(1) Slot blocked with a ferrous material to interrupt magnetic flux.

(2) See Hall-effect data sheet OH090 through OHS3100 Series for additional information — for reference only.



	Right	Right	Left	Left
	Operate	Release	Release	Operate
	Point	Point	Point	Point
Minimum	0.073"	0.045"	-0.045"	-0.073"
	[1,85mm]	[1,14mm]	[-1,14mm]	[-1,85mm]
Maximum Meas	0.003" [0,08mm] surements	-0.005" [-0.127mm] are refere		-0.003" [-0,08mm] enter Line.

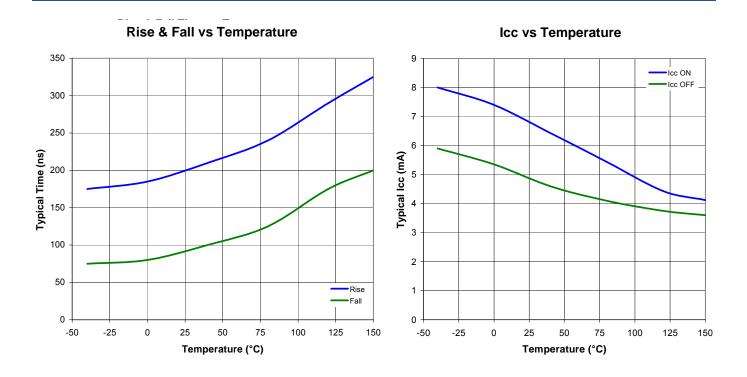


Vane - Material = 1018 Cold Rolled Steel - 0.03" [0.76mm] Thick Location = 0.50" [12.7mm] from Bottom of Slot

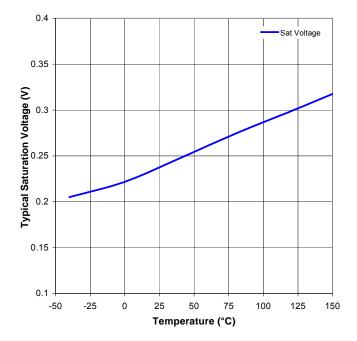
OPTEK reserves the right to make changes at any time in order to improve design and to supply the best product possible.

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Saturation Voltage vs Temperature



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